# R3000 THRU R5000

200mA 3000V~5000V--High voltage silicon rectifier diode

HVGT high voltage silicon rectifier diodes is made of high quality glass passivated chip and high reliability epoxy resin sealing structure, and through professional testing equipment inspection qualified after to customers.

#### **FEATURES:**

- 1. Low cost.
- 2. Low leakage.
- 3. Low forward voltage drop.
- 4. Conform to RoHS.
- 5. High current capability.

### **APPLICATIONS:**

- 1. High voltage multiplier circuit
- 2. Electrostatic generator circuit .
- 3. General purpose high voltage rectifier.
- 4. Other.

## **MECHANICAL DATA:**

Case: JEDEC DO-15 molded plastic body

Terminals: Plated axial leads, solderable per

MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any.

Weight: 0.014 ounce, 0.40 grams.

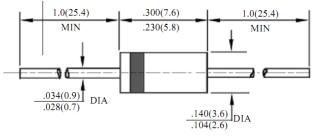
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SIZE: (Unit:mm)

HVGT NAME: DO-15

# **D0-15 Series**

Lead Diameter 0.9mm



Unit: inches / mm

## **MAXIMUM RATINGS AND CHARACTERISTICS:** (@ Ta= 25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbols	R3000	R4000	R5000	Units
Peak Repetitive Reverse Voltage	Vrrm				
Working Peak Reverse Voltage	Vrwm	3000	4000	5000	V
DC Blocking Voltage	VR				
RMS Reverse Voltage	Vr(rsm)	2100	2800	3500	V
Average Output Current (Note 1) @ TL = 50°C	Io	200			mA
Non-Repetitive Peak Forward Surge Current 8.3ms					
single half sine-wave superimposed on rated load	Ifsm	30			А
(JEDEC Method)			T		
Forward Voltage @ IF= 200mA	Vfm	4.0	5.0		V
Peak Reverse Leakage Current at Rated DC Blocking Voltage	Irm	5.0			uA
Typical Junction Capacitance (Note 2)	Сј	30			pF
Typical Thermal Resistance Junction to Ambient	Roja	117			K/W
Operating and Storage Temperature Range	ТЈ, Тѕтб	-65 to +150			°C

**Notes:** 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case. 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

SHAPE DISPLAY:



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